# 74AHC123A; 74AHCT123A

# Dual retriggerable monostable multivibrator with reset Rev. 4 — 8 November 2011 Product da

Product data sheet

#### **General description** 1.

The 74AHC123A; 74AHCT123A are high-speed Si-gate CMOS devices and are pin compatible with Low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74AHC123A; 74AHCT123A are dual retriggerable monostable multivibrators with output pulse width control by three methods. The basic pulse time is programmed by selection of an external resistor (R<sub>FXT</sub>) and capacitor (C<sub>FXT</sub>). The external resistor and capacitor are normally connected as shown in Figure 11.

Once triggered, the basic output pulse width may be extended by retriggering the gated active LOW-going edge input (nA) or the active HIGH-going edge input (nB). By repeating this process, the output pulse period (nQ = HIGH, nQ = LOW) can be made as long as desired. Alternatively an output delay can be terminated at any time by a LOW-going edge on input nRD, which also inhibits the triggering.

An internal connection from nRD to the input gate makes it possible to trigger the circuit by a positive-going signal at input nRD as shown in Table 3. Figure 8 and Figure 9 illustrate pulse control by retriggering and early reset. The basic output pulse width is essentially determined by the value of the external timing components R<sub>FXT</sub> and C<sub>FXT</sub>. When  $C_{EXT} \ge 10$  nF, the typical output pulse width is defined as:  $t_W = R_{EXT} \times C_{EXT}$  where  $t_W$  = pulse width in ns;  $R_{FXT}$  = external resistor in  $k\Omega$ ;  $C_{FXT}$  = external capacitor in pF. Schmitt-trigger action at all inputs makes the circuit highly tolerant to slower input rise and fall times.

#### **Features and benefits** 2.

- All inputs have a Schmitt-trigger action
- Inputs accept voltages higher than V<sub>CC</sub>
- DC triggered from active HIGH or active LOW inputs
- Retriggerable for very long pulses up to 100 % duty factor
- Direct reset terminates output pulse
- For 74AHC123A only: operates with CMOS input levels
- For 74AHCT123A only: operates with TTL input levels
- ESD protection:
  - HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V
  - CDM JESD22-C101C exceeds 1000 V
- Multiple package options
- Specified from –40 °C to +85 °C and from –40 °C to +125 °C

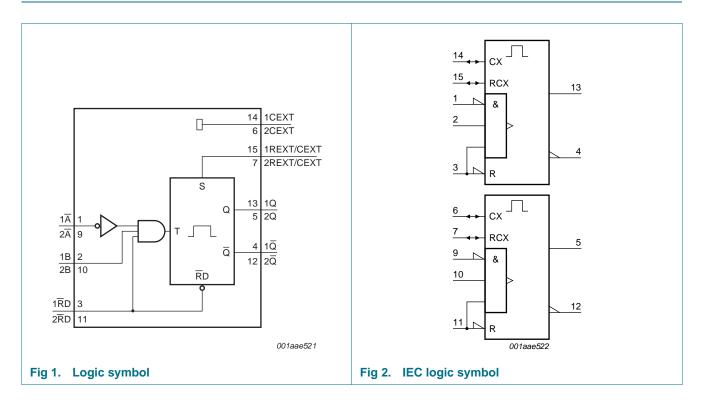


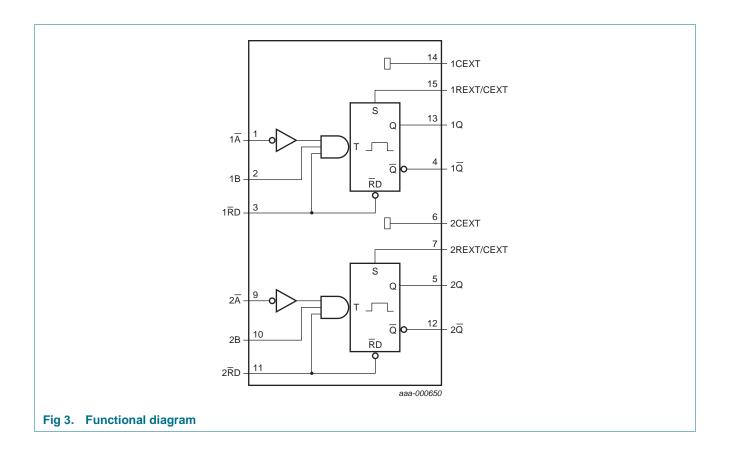
### 3. Ordering information

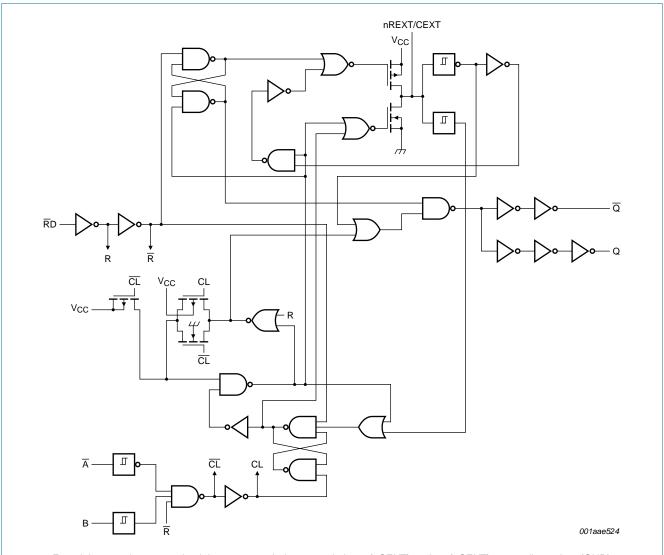
Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74AHC123AD	−40 °C to +125 °C	SO16	plastic small outline package; 16 leads;	SOT109-1
74AHCT123AD			body width 3.9 mm	
74AHC123APW	-40 °C to +125 °C TSSOP16 plastic thin shrink small outline package; 16 leads; S		SOT403-1	
74AHCT123APW			body width 4.4 mm	
74AHC123ABQ	–40 °C to +125 °C	DHVQFN16	plastic dual in-line compatible thermal enhanced	SOT763-1
74AHCT123ABQ			very thin quad flat package; no leads; 16 terminals; body $2.5 \times 3.5 \times 0.85$ mm	

### 4. Functional diagram





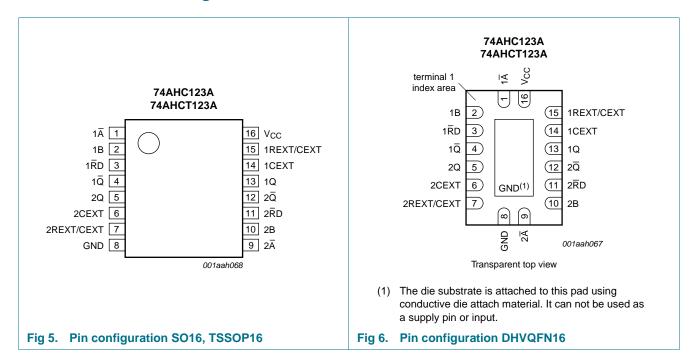


For minimum noise generation it is recommended to ground pins 6 (2CEXT) and 14 (1CEXT) externally to pin 8 (GND).

Fig 4. Functional diagram

#### 5. Pinning information

#### 5.1 Pinning



#### 5.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
1Ā	1	negative-edge triggered input 1
1B	2	positive-edge triggered input 1
1RD	3	direct reset LOW and positive-edge triggered input 1
1Q	4	active LOW output 1
2Q	5	active HIGH output 2
2CEXT	6	external capacitor connection 2
2REXT/CEXT	7	external resistor and capacitor connection 2
GND	8	ground (0 V)
2 <del>A</del>	9	negative-edge triggered input 2
2B	10	positive-edge triggered input 2
2RD	11	direct reset LOW and positive-edge triggered input 2
2Q	12	active LOW output 2
1Q	13	active HIGH output 1
1CEXT	14	external capacitor connection 1
1REXT/CEXT	15	external resistor and capacitor connection 1
V <sub>CC</sub>	16	supply voltage

#### 6. Functional description

Table 3. Function table[1]

Input			Output	
nRD	nΑ	nB	nQ	nQ
L	X	X	L	Н
X	Н	Χ	[2]	H[2]
X	Χ	L	[2]	H[2]
Н	L	$\uparrow$	Л	T
Н	<b>\</b>	Н	Л	T
$\uparrow$	L	Н	Л	IJ

<sup>[1]</sup> H = HIGH voltage level;

L = LOW voltage level;

= one HIGH level output pulse;

= one LOW level output pulse.

#### 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+7.0	V
VI	input voltage		-0.5	+7.0	V
I <sub>IK</sub>	input clamping current	$V_1 < -0.5 V$	<u>[1]</u> –20	-	mA
I <sub>OK</sub>	output clamping current	$V_O < -0.5 \text{ V or } V_O > V_{CC} + 0.5 \text{ V}$	<u>[1]</u> -	±20	mA
Io	output current	$V_{O} = -0.5 \text{ V to } (V_{CC} + 0.5 \text{ V})$	-	±25	mA
I <sub>CC</sub>	supply current		-	75	mA
I <sub>GND</sub>	ground current		<b>-75</b>	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40  ^{\circ}\text{C} \text{ to } +125  ^{\circ}\text{C}$			
	SO16 package		[2] _	500	mW
	TSSOP16 package		[3] _	500	mW
	DHVQFN16 package		[4] _	500	mW

<sup>[1]</sup> The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

74AHC\_AHCT123A

X = don't care;

<sup>↑ =</sup> LOW-to-HIGH transition;

 $<sup>\</sup>downarrow$  = HIGH-to-LOW transition;

<sup>[2]</sup> If the monostable multivibrator was triggered before this condition was established, the pulse will continue as programmed.

<sup>[2]</sup> Ptot derates linearly with 8 mW/K above 70 °C.

<sup>[3]</sup> P<sub>tot</sub> derates linearly with 5.5 mW/K above 60 °C.

<sup>[4]</sup> Ptot derates linearly with 4.5 mW/K above 60 °C.

### 8. Recommended operating conditions

Table 5. Recommended operating conditions

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	74AHC1	123A		74AHC1	Г123А		Unit
			Min	Тур	Max	Min	Тур	Max	
$V_{CC}$	supply voltage		2.0	5.0	5.5	4.5	5.0	5.5	V
VI	input voltage		0	-	5.5	0	-	5.5	V
Vo	output voltage		0	-	$V_{CC}$	0	-	$V_{CC}$	V
T <sub>amb</sub>	ambient temperature		-40	+25	+125	-40	+25	+125	°C
Δt/ΔV	input transition rise	$V_{CC}$ = 3.3 V $\pm$ 0.3 V	-	-	100	-	-	-	ns/V
	and fall rate	$V_{CC} = 5.0 \text{ V} \pm 0.5 \text{ V}$	-	-	20	-	-	20	ns/V

#### 9. Static characteristics

Table 6. Static characteristics

Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		25 °C	2	-40 °C	to +85 °C	–40 °C t	o +125 °C	Unit
			Min	Тур	Max	Min	Max	Min	Max	
74AHC1:	23A								1	1
V <sub>IH</sub>	HIGH-level	V <sub>CC</sub> = 2.0 V	1.5	-	-	1.5	-	1.5	-	V
	input voltage	V <sub>CC</sub> = 3.0 V	2.1	-	-	2.1	-	2.1	-	V
		V <sub>CC</sub> = 5.5 V	3.85	-	-	3.85	-	3.85	-	V
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 2.0 V	-	-	0.5	-	0.5	-	0.5	V
	input voltage	V <sub>CC</sub> = 3.0 V	-	-	0.9	-	0.9	-	0.9	V
	HIGH-level	V <sub>CC</sub> = 5.5 V	-	-	1.65	-	1.65	-	1.65	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$								
	output	$I_{O} = -50 \mu A; V_{CC} = 2.0 V$	1.9	2.0	-	1.9	-	1.9	-	V
	voltage	$I_{O} = -50 \mu A; V_{CC} = 3.0 V$	2.9	3.0	-	2.9	-	2.9	-	V
		$I_{O} = -50 \mu A; V_{CC} = 4.5 V$	4.4	4.5	-	4.4	-	4.4	-	V
		$I_O = -4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.58	-	-	2.48	-	2.40	-	V
		$I_O = -8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	3.94	-	-	3.8	-	3.70	-	V
$V_{OL}$	LOW-level	$V_I = V_{IH}$ or $V_{IL}$								
	output voltage	$I_O = 50 \mu A; V_{CC} = 2.0 V$	-	0	0.1	-	0.1	-	0.1	V
	voitage	$I_O = 50 \mu A; V_{CC} = 3.0 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 50 \mu A; V_{CC} = 4.5 V$	-	0	0.1	-	0.1	-	0.1	V
		$I_O = 4.0 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
		$I_O = 8.0 \text{ mA}; V_{CC} = 4.5 \text{ V}$	-	-	0.36	-	0.44	-	0.55	V
I <sub>I</sub>	input leakage current	$V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$								
		nREXT/CEXT	[1] -	-	±0.25	-	±2.5	-	±10.0	μΑ
		pins nA, nB, nRD	-	-	±0.1	-	±1.0	-	±2.0	μΑ

**Table 6. Static characteristics** ...continued Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions			25 °C	;	-40 °C 1	to +85 °C	-40 °C t	o +125 °C	Unit
				Min	Тур	Max	Min	Max	Min	Max	
Icc	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$		-	-	4.0	-	40	-	80	μА
		active state (per circuit); V <sub>I</sub> = V <sub>CC</sub> or GND	[1]								
		V <sub>CC</sub> = 3.0 V		-	160	250	-	280	-	280	μΑ
		V <sub>CC</sub> = 4.5 V		-	380	500	-	650	-	650	μΑ
		V <sub>CC</sub> = 5.5 V		-	560	750	-	975	-	975	μΑ
Cı	input capacitance			-	5.0	10	-	10	-	10	pF
Co	output capacitance			-	4.0	-	-	-	-	-	pF
74AHCT	123A										
V <sub>IH</sub>	HIGH-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		2.0	-	-	2.0	-	2.0	-	V
V <sub>IL</sub>	LOW-level input voltage	$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	-	8.0	-	8.0	-	0.8	V
V <sub>OH</sub>	HIGH-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$									
	output voltage	$I_{O} = -50 \ \mu A$		4.4	4.5	-	4.4	-	4.4	-	٧
		$I_{O} = -8.0 \text{ mA}$		3.94	-	-	3.8	-	3.70	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$ ; $V_{CC} = 4.5 \text{ V}$									
	output voltage	$I_O = 50 \mu A$		-	0	0.1	-	0.1	-	0.1	V
	voitage	$I_0 = 8.0 \text{ mA}$		-	-	0.36	-	0.44	-	0.55	V
l <sub>l</sub>	input leakage current	nREXT/CEXT; $V_I = 5.5 \text{ V or GND};$ $V_{CC} = 0 \text{ V to } 5.5 \text{ V}$	[1]	-	-	±0.25	-	±2.5	-	±10.0	μΑ
		pins $n\overline{A}$ , $nB$ , $n\overline{RD}$ ; $V_1 = V_{CC}$ or GND; $V_{CC} = 5.5 \text{ V}$		-	-	±0.1	-	±1.0	-	±2.0	μА
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 5.5 \text{ V}$		-	-	4.0	-	40	-	80	μА
		active state (per circuit); V <sub>I</sub> = V <sub>CC</sub> or GND	[1]								
		V <sub>CC</sub> = 4.5 V		-	380	500	-	650	-	650	μΑ
		V <sub>CC</sub> = 5.5 V		-	560	750	-	975	-	975	μΑ
Cı	input capacitance			-	3	10	-	10	-	10	pF
Co	output capacitance			-	4.0	-	-	-	-	-	pF

<sup>[1]</sup> Voltage on nREXT/CEXT =  $0.5 \times V_{CC}$  and pin nREXT/CEXT in OFF-state during test.

### 10. Dynamic characteristics

Table 7. Dynamic characteristics

GND = 0 V; For test circuit see Figure 12.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C t	o +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
74AHC1	23A		,				'	'	1	1	
t <sub>pd</sub>	propagation delay	$n\overline{A}$ and $nB$ to $nQ$ and $n\overline{Q}$ ; see Figure 7	[2]								
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$									
		$C_L = 15 pF$		-	7.4	20.6	1.0	24.0	1.0	26.0	ns
		$C_L = 50 pF$		-	10.5	24.1	1.0	27.5	1.0	30.0	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		$C_L = 15 pF$		-	5.1	12.0	1.0	14.0	1.0	15.5	ns
		$C_L = 50 pF$		-	7.3	14.0	1.0	16.0	1.0	17.5	ns
		$\overline{NRD}$ to $\overline{NRD}$ to $\overline{NRD}$ ; see Figure 7	[2]								
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$									
		C <sub>L</sub> = 15 pF		-	8.2	22.4	1.0	26.0	1.0	28.0	ns
		$C_L = 50 pF$		-	11.7	25.9	1.0	29.5	1.0	32.0	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		C <sub>L</sub> = 15 pF		-	5.6	12.9	1.0	15.0	1.0	16.5	ns
		$C_L = 50 pF$		-	8.1	14.9	1.0	17.0	1.0	19.0	ns
		$\overline{NRD}$ to $\overline{NRD}$ to $\overline{NRD}$ (reset); see Figure 7	[2]								
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$									
		C <sub>L</sub> = 15 pF		-	6.4	15.8	1.0	18.5	1.0	20.0	ns
		$C_L = 50 pF$		-	9.2	19.3	1.0	22.0	1.0	24.5	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		C <sub>L</sub> = 15 pF		-	4.4	9.4	1.0	11.0	1.0	12.0	ns
		C <sub>L</sub> = 50 pF		-	6.3	11.4	1.0	13.0	1.0	14.5	ns

**Table 7. Dynamic characteristics** ...continued GND = 0 V; For test circuit see <u>Figure 12</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C t	to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
$t_{W}$	pulse width	inputs; $n\overline{A} = LOW$ ; see Figure 7									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		inputs; nB = HIGH; see <u>Figure 7</u>									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		inputs; nRD = LOW; see <u>Figure 7</u>									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		outputs; $n\overline{Q}$ = LOW and $nQ$ = HIGH; $C_L$ = 50 pF; see Figure 7, Figure 8, Figure 9 and Figure 10	[3]								
		$C_{EXT}$ = 28 pF; $R_{EXT}$ = 2 k $\Omega$									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	115	240	-	300	-	300	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	100	200	-	240	-	240	ns
		$C_{EXT} = 0.01 \mu F;$ $R_{EXT} = 10 k\Omega$									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		90	100	110	90	110	85	115	μS
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		90	100	110	90	110	85	115	μS
		$C_{EXT} = 0.1 \mu F;$ $R_{EXT} = 10 k\Omega;$									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		0.9	1	1.1	0.9	1.1	0.85	1.15	ms
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.9	1	1.1	0.9	1.1	0.85	1.15	ms
t <sub>rtrig</sub>	retrigger time	$\overline{\text{NA}}$ to nB; $C_{\text{EXT}}$ = 100 pF; $R_{\text{EXT}}$ = 1 k $\Omega$ ; $C_{\text{L}}$ = 50 pF; see <u>Figure 8</u> and <u>Figure 10</u>									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	60	-	-	-	-	-	ns
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	39	-	-	-	-	-	ns
		$\overline{\text{nA}}$ to nB; $C_{\text{EXT}}$ = 0.01 $\mu\text{F}$ ; $R_{\text{EXT}}$ = 1 $k\Omega$ ; $C_{\text{L}}$ = 50 pF; see Figure 8 and Figure 10									
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		-	1.5	-	-	-	-	-	μS
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	1.2	-	-	-	-	-	μS
C <sub>PD</sub>	power dissipation capacitance	$C_L = 50 \text{ pF}; f_i = 1 \text{ MHz};$ $V_I = \text{GND to } V_{CC}$	<u>[4]</u>	-	57	-	-	-	-	-	pF

**Table 7. Dynamic characteristics** ...continued GND = 0 V; For test circuit see <u>Figure 12</u>.

Symbol	Parameter	Conditions			25 °C		-40 °C	to +85 °C	-40 °C 1	to +125 °C	Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
74AHCT	123A										
t <sub>pd</sub>	propagation delay	$n\overline{A}$ and $nB$ to $nQ$ and $n\overline{Q}$ ; see Figure 7	[2]								
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		C <sub>L</sub> = 15 pF		-	5.0	12.0	1.0	14.0	1.0	15.5	ns
		$C_L = 50 pF$		-	7.1	14.0	1.0	16.0	1.0	17.5	ns
		$\overline{nRD}$ to $\overline{nQ}$ and $\overline{nQ}$ ; see Figure 7	[2]								
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		$C_L = 15 pF$		-	5.2	12.9	1.0	15.0	1.0	16.5	ns
		$C_L = 50 pF$		-	7.5	14.9	1.0	17.0	1.0	18.5	ns
		$\overline{\text{NRD}}$ to $\overline{\text{nQ}}$ and $\overline{\text{nQ}}$ (reset); see Figure 7	[2]								
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$									
		C <sub>L</sub> = 15 pF		-	4.7	9.4	1.0	11.0	1.0	12.0	ns
		$C_L = 50 pF$		-	6.7	11.4	1.0	13.0	1.0	14.5	ns
t <sub>W</sub> p	pulse width	inputs; $n\overline{A} = LOW$ ; $C_L = 50 \text{ pF}$ ; see Figure 7									
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		inputs; nB = HIGH; C <sub>L</sub> = 50 pF; see <u>Figure 7</u>									
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		inputs; $\overline{NRD} = LOW$ ; $C_L = 50 \text{ pF}$ ; see Figure 7									
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		5.0	-	-	5.0	-	5.0	-	ns
		outputs; $n\overline{Q}$ = LOW and $nQ$ = HIGH; $C_L$ = 50 pF; $C_{EXT}$ = 28 pF; $R_{EXT}$ = 2 k $\Omega$ ; see <u>Figure 7</u> , <u>Figure 8</u> , <u>Figure 9</u> and <u>Figure 10</u>	[3]								
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	100	200	-	240	-	240	ns
		$C_{EXT} = 0.01 \mu F;$ $R_{EXT} = 10 k\Omega$									
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		90	100	110	90	110	85	115	μS
		$C_{EXT} = 0.1 \mu F;$ $R_{EXT} = 10 k\Omega$									
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		0.9	1	1.1	0.9	1.1	0.85	1.15	ms

**Table 7. Dynamic characteristics** ...continued GND = 0 V; For test circuit see Figure 12.

Symbol	Parameter	Conditions			25 °C		–40 °C 1	to +85 °C	-40 °C to +125 °C		Unit
				Min	Typ[1]	Max	Min	Max	Min	Max	
t <sub>rtrig</sub>	retrigger time	$\overline{\text{NA}}$ to nB; $C_{\text{EXT}}$ = 100 pF; $R_{\text{EXT}}$ = 1 k $\Omega$ ; $C_{\text{L}}$ = 50 pF; see <u>Figure 8</u> and <u>Figure 10</u>									
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	60	-	-	-	-	-	ns
		n $\overline{A}$ to nB; $C_{EXT}$ = 0.01 $\mu$ F; $R_{EXT}$ = 1 k $\Omega$ ; $C_L$ = 50 pF; see <u>Figure 8</u> and <u>Figure 10</u>									
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-	1.5	-	-	-	-	-	μS
$C_{PD}$	power dissipation capacitance	$C_L = 50 \text{ pF}$ ; $f_i = 1 \text{ MHz}$ ; $V_I = \text{GND to } V_{CC}$	<u>[4]</u>	-	58	-	-	-	-	-	pF
Externa	components	1									
R <sub>EXT</sub>	external	V <sub>CC</sub> = 2.0 V		5	-	-	-	-	-	-	kΩ
	resistance	V <sub>CC</sub> > 3.0 V		1	-	-	-	-	-	-	$k\Omega$
$C_{EXT}$	EXT external	V <sub>CC</sub> = 2.0 V	[5]	-	-	-	-	-	-	-	pF
		V <sub>CC</sub> > 3.0 V	[5]	-	-	-	-	-	-	-	pF

- [1] Typical values are measured at nominal supply voltage ( $V_{CC}$  = 3.3 V and  $V_{CC}$  = 5.0 V).
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ ;  $C_{EXT}$  = 0 pF;  $R_{EXT}$  = 5 k $\Omega$ .
- [3] For  $C_{EXT} \ge$  10 nF the typical value of the pulse width  $t_W$  ( $\mu$ s) =  $C_{EXT}$  (nF)  $\times$   $R_{EXT}$  ( $k\Omega$ ).
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation  $P_D$  ( $\mu W$ ).

$$P_D = C_{PD} \times V_{CC}{}^2 \times f_i + \sum (C_L \times V_{CC}{}^2 \times f_o)$$
 where:

 $f_i$  = input frequency in MHz;

f<sub>o</sub> = output frequency in MHz;

 $C_L$  = output load capacitance in pF;

 $V_{CC}$  = supply voltage in V.

[5]  $C_{\text{EXT}}$  has no limits.

#### 11. Waveforms

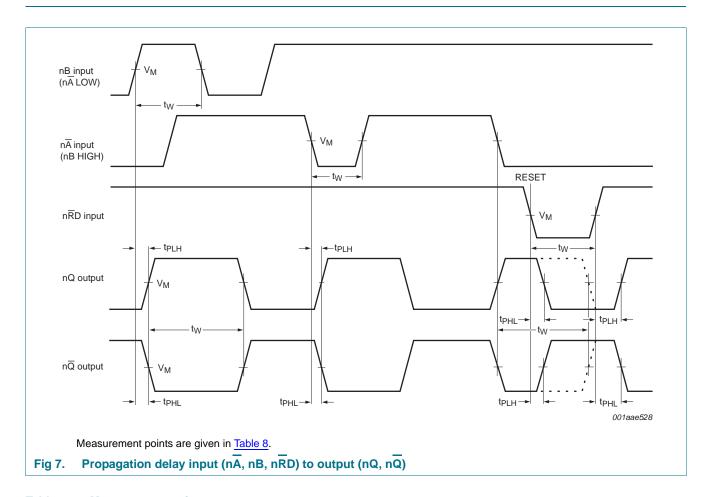
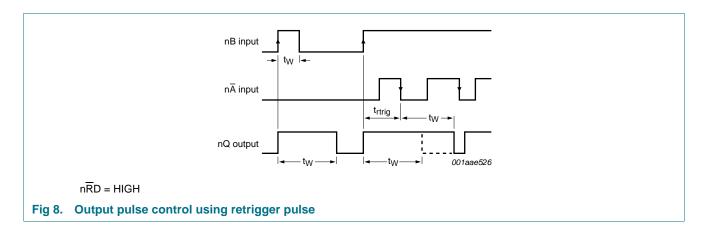
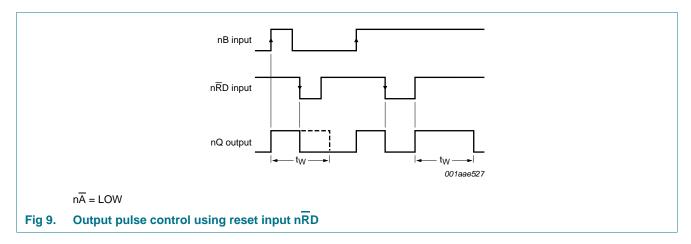


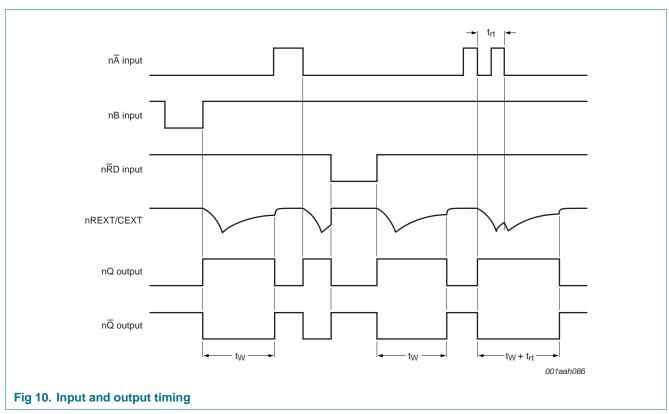
Table 8. Measurement points

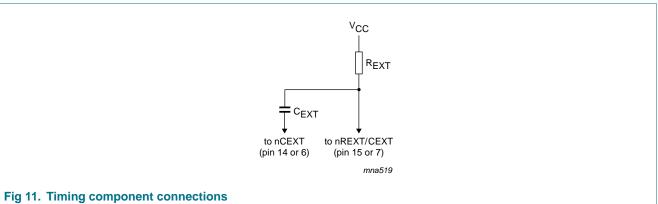
Туре	Input	Output
	V <sub>M</sub>	V <sub>M</sub>
74AHC123A	0.5V <sub>CC</sub>	0.5V <sub>CC</sub>
74AHCT123A	1.5 V	0.5V <sub>CC</sub>

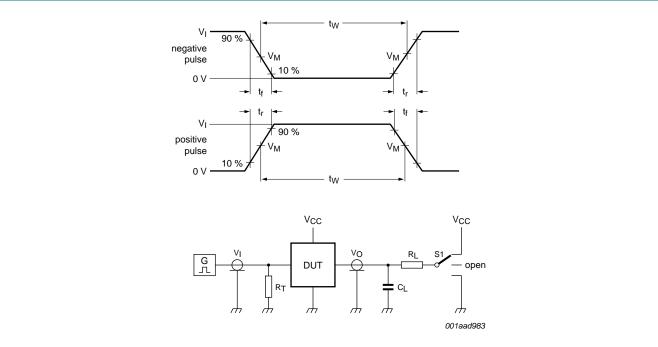


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Test data is given in Table 9.

Definitions test circuit:

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator

C<sub>L</sub> = Load capacitance including jig and probe capacitance

R<sub>L</sub> = Load resistor

S1 = Test selection switch

Fig 12. Load circuitry for switching times

Table 9. Test data

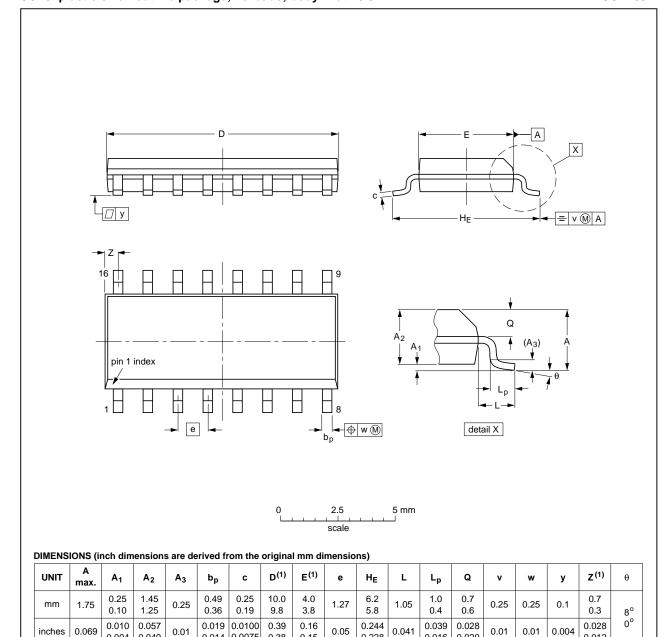
Туре	Input		Load		S1 position				
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	R <sub>L</sub>	t <sub>PHL</sub> , t <sub>PLH</sub>	t <sub>PZH</sub> , t <sub>PHZ</sub>	t <sub>PZL</sub> , t <sub>PLZ</sub>		
74AHC123A	$V_{CC}$	3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>		
74AHCT123A	3.0 V	3.0 ns	15 pF, 50 pF	1 kΩ	open	GND	V <sub>CC</sub>		

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#### 12. Package outline

#### SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1



1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.014 0.0075

0.38

0.15

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	IEC JEDEC JEITA					
SOT109-1	076E07	MS-012				<del>99-12-27</del> 03-02-19

0.228

Fig 13. Package outline SOT109-1 (SO16)

0.004

0.049

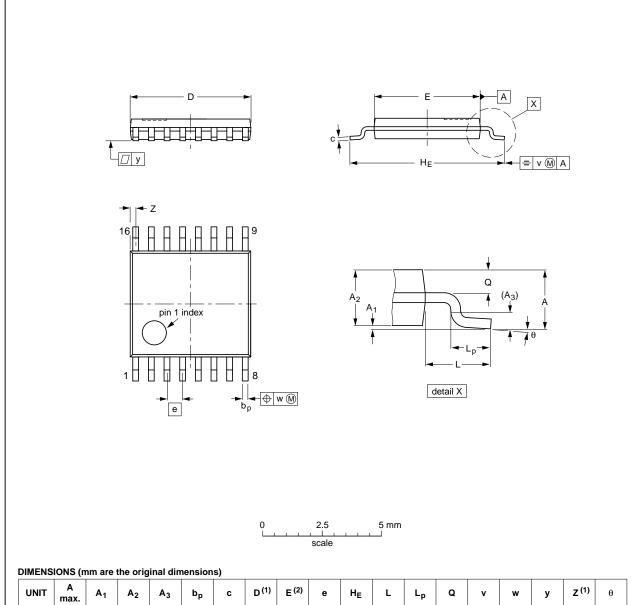
74AHC\_AHCT123A

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TSSOP16: plastic thin shrink small outline package; 16 leads; body width 4.4 mm

SOT403-1



1	SimErroroto (min are the original amensions)																		
	UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	С	D <sup>(1)</sup>	E <sup>(2)</sup>	е	HE	L	Lp	Q	v	w	у	Z <sup>(1)</sup>	θ
	mm	1.1	0.15 0.05	0.95 0.80	0.25	0.30 0.19	0.2 0.1	5.1 4.9	4.5 4.3	0.65	6.6 6.2	1	0.75 0.50	0.4 0.3	0.2	0.13	0.1	0.40 0.06	8° 0°

- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE		REFER	EUROPEAN	ISSUE DATE			
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT403-1		MO-153				<del>99-12-27</del> 03-02-18	

Fig 14. Package outline SOT403-1 (TSSOP16)

74AHC\_AHCT123A

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DHVQFN16: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 16 terminals; body 2.5 x 3.5 x 0.85 mm SOT763-1

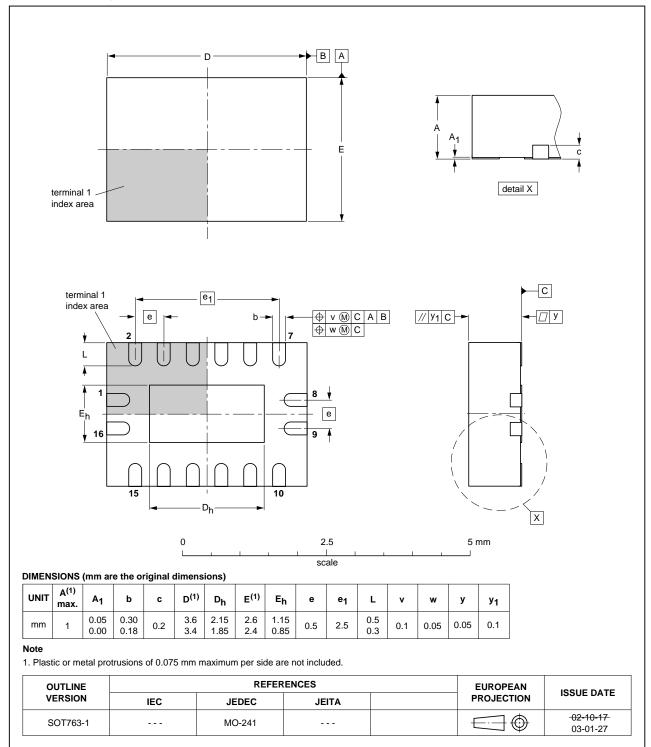


Fig 15. Package outline SOT763-1 (DHVQFN16)

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#### 13. Abbreviations

#### Table 10. Abbreviations

Acronym	Description
CDM	Charged-Device Model
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
НВМ	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

# 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74AHC_AHCT123A v.4	20111108	Product data sheet	-	74AHC_AHCT123A v.3
Modifications:	<ul> <li>Legal pages</li> </ul>	updated.		
74AHC_AHCT123A v.3	20110908	Product data sheet	-	74AHC_AHCT123A v.2
74AHC_AHCT123A v.2	20080118	Product data sheet	-	74AHC_AHCT123A v.1
74AHC_AHCT123A v.1	20000315	Product specification	-	-

#### 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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#### Dual retriggerable monostable multivibrator with reset

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